

15162

3 Hours / 100 Marks

Seat No.	
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Instructions:

- (1) All questions are compulsory.
- (2) Answer each next main question on a new page.
- (3) Illustrate your answers with neat sketches wherever necessary.
- (4) Figures to the **right** indicate **full** marks.
- (5) Assume suitable data, if necessary.
- (6) Mobile Phone, Pager and any other Electronic Communication devices are **not** permissible in Examination Hall.

Marks

1. Attempt any ten of the following:

20

- a) Write the four specifications of zener diode.
- b) State the applications of LED.
- c) Draw construction of bipolar junction transistor give size and doping concentration of each region.
- d) Define line regulation and load regulation.
- e) Draw symbol of D-MOSFET (n-channel and p-channel).
- f) State the concept of cross-over distortion.
- g) State typical values of knee voltage for silicon and germanium P-N junction.
- h) State the applications of FET (any four).
- i) List various transistor biasing methods.
- j) State the Bankhausen criteria of oscillations.
- k) Define gain and bandwidth of small signal amplifier.
- 1) Define amplification factor (μ) of JFET.
- m) Convert the following numbers.

i)
$$(5C7)_{16} = ()_{10}$$

ii)
$$(43)_8 = ($$
 $)_2$

n) Draw a symbol and truth table of NOR gate.



Marks

2. Attempt any four of the following:

16

- a) Draw a V-I characteristics of P-N junction diode in forward and reverse bias. Define static and dynamic resistance.
- b) Draw a circuit diagram of centre tapped full wave rectifier with series inductor filter. Draw its input and output waveforms.
- c) Compare CB and CE configurations with respect to input resistance, output resistance, voltage gain and current gain.
- d) Describe the voltage divider biasing technique of BJT with ckt. diagram.
- e) Describe the functional pin diagram of regulator IC 78XX and 79XX.
- f) Draw the circuit diagram of colpits oscillator. Explain its working principle. Write equation for output frequency.

3. Attempt any four of the following:

16

- a) Draw constructional details of Schottky diode draw its symbol and explain its working.
- b) Describe thermal runaway of transistor and explain how it can be avoided.
- c) Compare half wave, centre tap and bridge type full wave rectifier on the basis of
 - i) Ripple factor

ii) Rectification efficiency

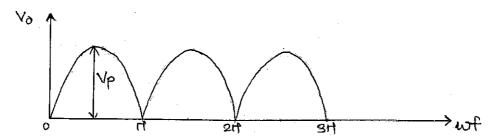
iii) TUF

- iv) Waveforms.
- d) Draw the circuit diagram of two stage transformer coupled amplifier and describe the function of each component.
- e) Draw the circuit diagram of transistorized shunt regulator circuit and describe its operation.
- f) Draw and describe working principle of RC phase shift oscillator. Write the equation for output frequency.

4. Attempt any four of the following:

16

- a) Draw a construction of LED and explain its working.
- b) In full wave rectifier $V_p = 10 \text{ V}$, $R_L = 10 \text{ k}\Omega$ find V_{DC} , I_{DC} and ripple factor.

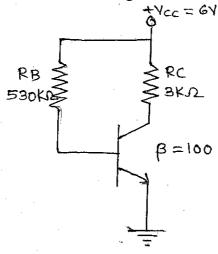


- c) Draw the circuit diagram of UJT relaxation oscillator. Sketch the output waveform and explain the operation of oscillator.
- d) Draw and explain constructional details of n-channel JFET.



Marks

e) Draw a dc load line for the following circuit and determine operating point.



f) Describe how zener diode is used as a voltage regulator.

5. Attempt any four of the following:

16

- a) Define feedback. Give the advantages of negative feedback.
- b) Draw a circuit diagram of class B push pull power amplifier. Sketch input and output waveform. Describe its operation.
- c) For a Hartley oscillator if C = 100 pF, $L_1 = 30 \,\mu\text{H}$, $L_2 = 1 \times 10^{-8} \,\text{H}$. Find the frequency of oscillation. Draw a circuit diagram of Hartley oscillator.
- d) Describe the working principle of enhancement type of n-channel MOSFET with diagrams.
- e) Using NAND gate only draw following:
 - i) OR gate

- ii) AND gate
- f) Describe the working of transistor as a switch with circuit diagram.

6. Attempt any four of the following:

16

- a) Draw a block diagram of regulated DC power supply and state the working of each block.
- b) Draw a frequency response of single stage amplifier and explain the effect of coupling capacitor and junction capacitance.
- c) Draw output characteristics in CE mode. Indicate DC load line with Q-point, saturation region and cut-off region.
- d) Derive the relation between α and β wrt BJT.
- e) Compare BJT and FET for four points.
- f) Describe EX-OR gate. Draw its symbol and Truth-table.